

ST755C

Adjustable inverting negative output current mode PWM regulators

Features

- 2.7V to 11V input to adjustable negative output conversion
- 1W guaranteed output power (V_I > 4.5V, T_A ≤70°C)
- 68% typ. efficiency at 6V
- Very low quiescent current: 1.2mA in on mode, 10µA in shut down mode
- Soft start
- Very low noise output
- 160KHz fixed frequency oscillator
- Mixed bipolar-CMOS technology

Description

The ST755 is an adjustable inverting switch-mode DC-DC regulator with internal Power MOSFET that generators an adjustable negative output from a voltage input of 2.7V to 11V, output current guaranteed at 200mA (for $V_1 > 4.5V$, $V_0 = -5V$



and T_A = 0°C to 70°C) and 275mA (typical value at T_A = 25°C, V_O = -5V).

A logic controlled shut down pin that interfaces directly with microprocessor educes supply current to only 10mA. Input to Output differential voltage is limited to V_I +IV_OI<12.7V. No load supply current to 1.2mA

Part number	Package	Packaging
ST755C	ST755CD-TR	SO-8 (tape & reel)

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1 Diagram





2 Pin configuration

Figure 2.	Pin connections	(top	view)
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	Pin desc	ription
Pin N°	Symbol	Name and function
1	SHDN	SHUT-DOWN control (V _{CC} = ON, GND = Shutdown)
2	V _{REF}	Reference output voltage: (1.25V)
3	SS	Soft start
4	CC	Compensation input
5	Vo	Negative output voltage
6	GND	Ground
7	LX	Switch output
8	V _{CC}	Supply voltage input
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~SO		

3 Maximum ratings

Table 3.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V _{CC}	DC input voltage to GND ⁽¹⁾	-0.3 to 12	V
V _{SHDN}	Shutdown voltage, SS Voltage, CC Voltage	-0.3 to (V _{CC} + 0.3)	V
V _{LX}	Switch voltage (LX to V_{CC})	-12.5 to + 0.3	V
V _{FB}	Feedback voltage (V _O to GND)	-11 to + 0.9	V
I _{LX}	Peak switch current	2	A
P _{TOT}	Continuous power dissipation at $T_A = 70^{\circ}C$ (SO-8)	470	mW
T _{op}	Operating junction temperature range (C series)	-40 to 185	°C
T _{stg}	Storage temperature range	-55 to +150	°C

1. The input to output differential voltage is limited to V_{CC} + $|V_O|$ <12.7V

Note: Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied

Table 4. Thermal data

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Symbol	Parameter	, ete	SO-8	Unit
R _{thJA}	Thermal resistance junction-ambient ⁽¹⁾		160	°C/W

1. This value depends from thermal design of PCB on which the device is mounted.

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4 Electrical characteristics

Table 5.Electrical characteristics (Refer to the test circuits, $V_{CC} = 5V$, $V_O = -5.25$ to -4.75V,
 $I_{LOAD} = 0mA$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical value are referred at
 $T_A = 25^{\circ}C$)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
VI	Input voltage		4		11	V
Vo	Output voltage	V_{CC} = 4.5 to 6.2V, I _O =0 to 200mA	4.75	5	5.25	V
		V_{CC} = 4.5 to 6.2V, T_A = 0 to 70°C	200	275		
		V_{CC} = 4.5 to 6.2V, T_A = -40 to 85°C	175			
ю		$V_{CC} = 4V, V_{O} = -5V$		175		- MA
		$V_{\rm CC}$ = 2.7V, $V_{\rm O}$ = -5V		125		
I _{SUPPLY}	Supply current (including switching current)	No Load, V _{SHDN} = V _{CC}		1.2	3.5	mA
I _{OFF}	Standby current)	No Load, V _{SHDN} = 0V		10	100	μA
I _{SC}	Short circuit current)			1.2	70.	Α
ΔV _O	Line regulation	V _{CC} = 4 to 6.2V		0.1		%/V
ΔV _O	Load regulation	I _O = 0 to 200mA	V	0.003		%/mA
V _{REF}	Reference voltage	$T_A = 25^{\circ}C$	1.18	1.25	1.32	V
ΔV_{REF}	Reference drift	$T_A = T_{MIN}$ to T_{MAX}		50		ppm/°C
R _{DSON}	LX on resistance	->5		0.7		Ω
I _{LEAK}	LX leakage current)	V _{DS} = 10V		1		μA
I _{SH}	Shutdown pin current)				1	μA
V _{IH}	SHDN input high threshold	.(5)	2			V
V _{IL}	SHDN input low threshold	SIL			0.25	V
f _{OSC}	Oscillator frequency			160		KHz
h	Power efficiency	I _O =100mA		68		%
сс	Compensation pin impedance			7.5		KΩ

Note:

Do not overload or short the Output to Ground. If the above conditions are observed, the device may be damaged.

5 Application information

The ST755 is an IC developed for voltage conversion from an input voltage ranging from +2.4V to 11V to a regulated adjustable negative output limited by $|V_O| \le 12.7V - V_I$. The circuit adopts a current-mode PWM control scheme to achieve good efficiency, high stability and low noise performance. The figure in the first page shown the detailed block diagram of the device.

ST755 is realized in a BCD technology in order to achieve high temperature stability, the best REFERENCE precision, a very low quiescent current and jitter free operations. The final stage is built around a 0.7 Ω - 2A P-Channel Power MOS. A fraction of the output current is splitted out for current detection. Internal clock frequency is fixed to 160KHz. Error amplifier drives the PWM comparator in order to keep 0V on the CC input. So R₃ and R₄ resistors are calculated by the following formulae $R_4 = (|V_O|/V_{REF})^*R_3$ (see *Figure 3*.). For R_3 can be choose any value between $2K\Omega$ and $20K\Omega$ Soft-Start (SS) input is a voltage dependent-output current limit (see Figure 11., Switch Current Limit vs. SS Input Voltage). SS pin is internally pulled to V_{REF} through a 1.2 M Ω resistor. Applying an appropriate capacitor at SS input is possible to obtain a soft-start current imitation during power up. Forcing Soft-Start (SS) input to a lower voltage through a resistive voltage driver (R1 and auced to obsolete product(s) - Obsolete prod R₂), the maximum LX current limit can be lowered according the diagram showed in *Figure* 11. When SHDN input is low, the total current consumption is reduced to 10µA.

6 Application circuit

To achieve the best performances from switching power supply topology, particular care to layout drawing is needed, in order to minimize EMI and obtain low noise, jitter free operation moreover, it ensures the full device functionality. Layout design proposed on demoboard (see *Figure 4.*) helps to lower the developing time. Wire lengths must be minimized, filter and by-pass capacitors C_1 , C_2 and C_3 must be low ESR type, placed as close possible to the integrated circuit. The 10µH inductor must be chosen built on a core, taking care that saturation current should be higher than the peak LX switch current. See the Peak inductor current vs. load current graph (*Figure 6.*).



Figure 3. Typical application circuit

(*) R1 and R2 can be omitted for I_O<200mA.

(**) C6: Very low noise but poor transient and load response speed.

**) C3 (alternative to C6): faster transient and load response.



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Figure 4. Printed demoboard



Note: Drawings not in scale

Table 6.Component values

Capacitor	Value	Unit	Resistor	Value	Unit
C1	47	μF	R1	130	KΩ
C2	100	μF	R2	300	KΩ
C3	82	pF	R3	10	KΩ
C4	1	μF	R4	40.7	KΩ
C5	10	μF	R5	10	KΩ
C6	47	pF	<u> </u>		

47 p ductis

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7 Typical performance characteristics



Figure 11. Switch current limit vs soft start voltage

Figure 12. Reference voltage vs temperature



Figure 13. Soft start delay time



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8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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	SO-8 MECHANICAL DATA						
DIM		mm.			inch		
DIN.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.04		0.010	
A2	1.10		1.65	0.043		0.065	
В	0.33		0.51	0.013		0.020	
С	0.19		0.25	0.007		0.010	
D	4.80		5.00	0.189		0.197	
E	3.80		4.00	0.150		0.157	
е		1.27			0.050		
Н	5.80		6.20	0.228		0.244	
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
k		•	8° (1	max.)		•	
ddd			0.1			0.04	



DIM		mm.			inch		
DIN.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
т			22.4			0.882	
Ao	8.1		8.5	0.319		0.335	
Во	5.5		5.9	0.216		0.232	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	





9 Revision history

Table 7. Revision history

Date	Revision	Changes
06-Jul-2007	5	Device summary updated and the document has been reformatted.

Obsolete Product(s). Obsolete Product(s)



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